

HIGH EFFICIENCY RECTIFIERS

VOLTAGE RANGE: 400 --- 600 V
CURRENT: 1.0 A

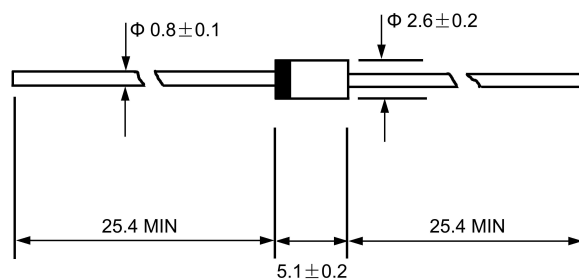
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO--41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

DO - 41



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ERC38 - 04	ERC38 - 05	ERC38 - 06	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	400	500	600	V
Maximum RMS voltage	V_{RMS}	280	350	420	V
Maximum DC blocking voltage	V_{DC}	400	500	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.0			A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	40.0			A
Maximum instantaneous forward voltage @ 1.0A	V_F	2.5			V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	5.0 50.0			μA
Maximum reverse recovery time (Note1)	t_{rr}	50			ns
Typical junction capacitance (Note2)	C_J	20		15	pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	60			$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ----- + 150			$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ----- + 150			$^\circ\text{C}$

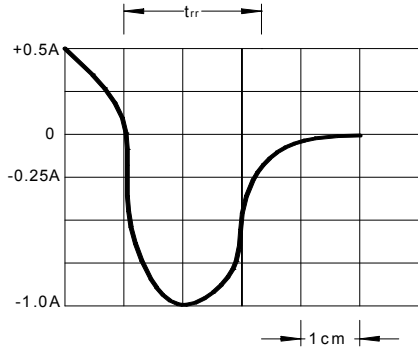
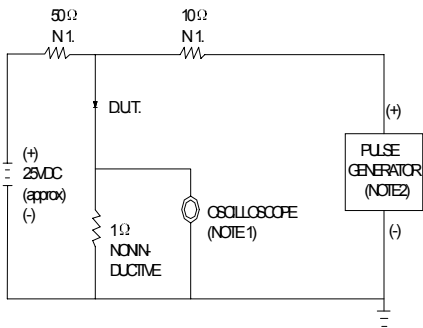
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $t_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1--TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME=7ns MAX.INPUT IMPEDANCE=1MΩ.22pF
2. RISE TIME=10ns MAX.SOURCE IMPEDANCE=50Ω.

SET TIME BASE FOR 20/30 ns/cm

FIG.2 --FORWARD DERATING CURVE

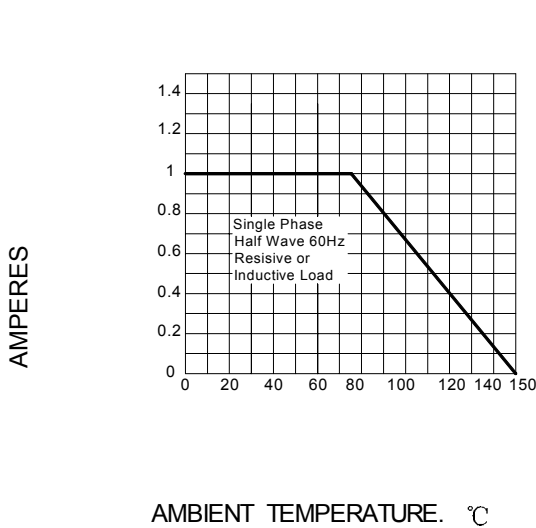


FIG.3--TYPICAL JUNCTION CAPACITANCE

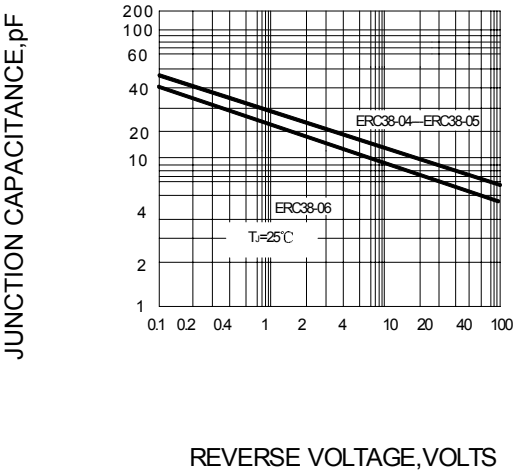


FIG.4--PEAK FORWARD SURGE CURRENT

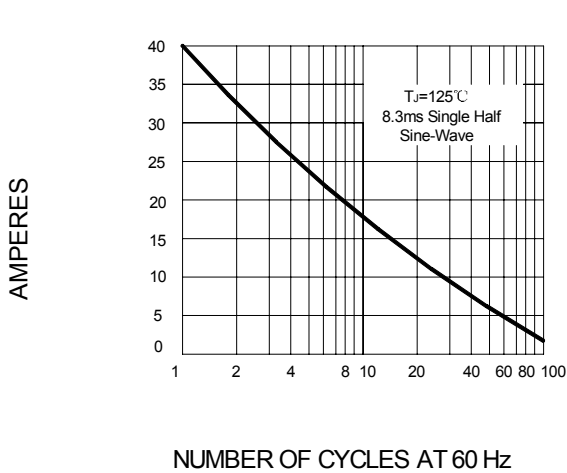


FIG.5 -- TYPICAL FORWARD CHARACTERISTIC

